

MC78XXE/LM78XXE/MC78XXAE

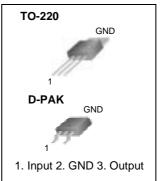
3-Terminal 1A Positive Voltage Regulator

Features

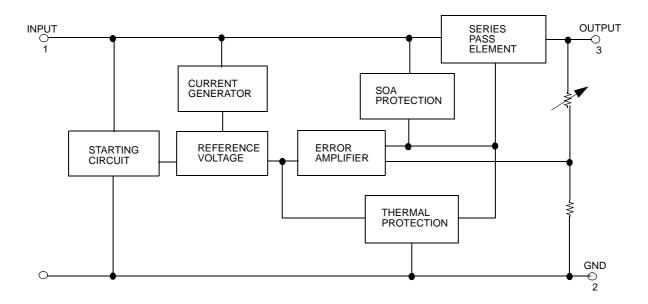
- Output Current up to 1A
- Output Voltages of 5, 6, 8, 9, 12, 15, 18, 24V
- Thermal Overload Protection
- · Short Circuit Protection
- Output Transistor Safe Operating Area Protection

Description

The MC78XXE/LM78XXE/MC78XXAE series of three terminal positive regulators are available in the TO-220/D-PAK package and with several fixed output voltages, making them useful in a wide range of applications. Each type employs internal current limiting, thermal shut down and safe operating area protection, making it essentially indestructible. If adequate heat sinking is provided, they can deliver over 1A output current. Although designed primarily as fixed voltage regulators, these devices can be used with external components to obtain adjustable voltages and currents.



Internal Block Digram



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Input Voltage (for V _O = 5V to 18V) (for V _O = 24V)	V _I V _I	35 40	V V
Thermal Resistance Junction-Cases (TO-220)	R _θ JC	5	°C/W
Thermal Resistance Junction-Air (TO-220)	RθJA	65	°C/W
Operating Temperature Range	Topr	0 ~ +125	°C
Storage Temperature Range	TSTG	-65 ~ +150	°C

Electrical Characteristics (MC7805E/LM7805E)

(Refer to test circuit ,0°C < TJ < 125°C, IO = 500mA, VI = 10V, CI= 0.33 μ F, CO= 0.1 μ F, unless otherwise specified)

Devementes	Councile of			MC78	05E/LM	7805E	Unit	
Parameter	Symbol		onditions	Min.	Тур.	Max.	Unit	
		T _J = +25°C		4.8	5.0	5.2		
Output Voltage	Vo	$5.0\text{mA} \le \text{lo} \le 1.0\text{A}, \text{PO} \le 15\text{W}$ V _I = 7V to 20V		4.75	5.0	5.25	V	
Line Regulation (Note1)	Regline	T _J = +25°C	V _O = 7V to 25V	-	4.0	100	mV	
Line Regulation (Note I)	Regilile	1J = +25 C	V _I = 8V to 12V	-	1.6	50	IIIV	
			Io = 5.0mA to1.5A	-	9	100		
Load Regulation (Note1)	Regload	TJ = +25°C	d TJ = +25°C	IO =250mA to 750mA	-	4	50	mV
Quiescent Current	IQ	T _J = +25°C		-	5.0	8.0	mA	
Quiescent Current Change	Alo	I _O = 5mA to 1.	0A	-	0.03	0.5	mA	
Quiescent Current Change	ΔlQ	VI = 7V to 25V	1	-	0.3	1.3	ША	
Output Voltage Drift (Note2)	ΔV0/ΔΤ	Io = 5mA		-	-0.8	-	mV/°C	
Output Noise Voltage	VN	f = 10Hz to 10	0kHz, TA = +25°C	-	42	-	μV/Vo	
Ripple Rejection (Note2)	RR	f = 120Hz Vo = 8V to 18	f = 120Hz Vo = 8V to 18V		73	-	dB	
Dropout Voltage	V _{Drop}	I _O = 1A, T _J =+25°C		-	2	-	V	
Output Resistance (Note2)	rO	f = 1kHz		-	15	-	mΩ	
Short Circuit Current	Isc	V _I = 35V, T _A =+25°C		-	230	-	mA	
Peak Current (Note2)	IPK	TJ = +25°C		-	2.2	-	Α	

^{1.} Load and line regulation are specified at constant junction temperature. Changes in V₀ due to heating effects must be taken into account separately. Pulse testing with low duty is used.

^{2.} These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (MC7806E) (Continued)

(Refer to test circuit ,0°C < T_J < 125°C, I_O = 500mA, V_I =11V, C_I= $0.33\mu F$, C_O= $0.1\mu F$, unless otherwise specified)

Donomoton	Councile of			N	1C7806	E	Unit	
Parameter	Symbol		Conditions		Тур.	Max.	Unit	
		T _J = +25°C	5.75	6.0	6.25			
Output Voltage	Vo	5.0mA ≤ I _O ≤ V _I = 8.0V to 21	1.0A, P _O ≤ 15W V	5.7	6.0	6.3	V	
Line Regulation (Note1)	Regline	T _J =+25°C	V _I = 8V to 25V	-	5	120	mV	
Line Regulation (Note I)	Regille	1J=+25 C	V _I = 9V to 13V	-	1.5	60	IIIV	
Load Population (Note1)	Poglood	T 25°C	Io =5mA to 1.5A	-	9	120	mV	
Load Regulation (Note1)	Regioad		Regload T _J =+25°C	IO =250mA to750A	-	3	60	IIIV
Quiescent Current	IQ	TJ =+25°C		-	5.0	8.0	mA	
Quiagont Current Change	Ale	IO = 5mA to 1A		-	-	0.5	mA	
Quiescent Current Change	ΔlQ	V _I = 8V to 25V		-	-	1.3	IIIA	
Output Voltage Drift (Note2)	ΔV0/ΔΤ	IO = 5mA		-	-0.8	-	mV/°C	
Output Noise Voltage	VN	f = 10Hz to 100k	Hz, T _A = +25°C	-	45	-	μV/Vo	
Ripple Rejection (Note2)	RR	f = 120Hz V _I = 9V to 19V			75	-	dB	
Dropout Voltage	VDrop	IO = 1A, TJ = +25°C		-	2	-	V	
Output Resistance (Note2)	rO	f = 1kHz		-	19	-	mΩ	
Short Circuit Current	Isc	V _I = 35V, T _A = -	+25°C	-	250	-	mA	
Peak Current (Note2)	IPK	TJ =+25°C		-	2.2	-	Α	

^{1.} Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

^{2.} These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (MC7808E) (Continued)

(Refer to test circuit $,0^{\circ}$ C < T_J < 125°C, I_O = 500mA, V_I =14V, C_I= 0.33 μ F, C_O= 0.1 μ F, unless otherwise specified)

Parameter	Symbol	C	onditions	M	C7808	E	Unit
Parameter	Syllibol		onditions	Min.	Тур.	Max.	Unit
		T _J =+25°C		7.7	8.0	8.3	
Output Voltage	Vo	_	$5.0\text{mA} \le I_{O} \le 1.0\text{A}, P_{O} \le 15\text{W}$ V _I = 10.5V to 23V		8.0	8.4	V
Line Regulation (Note1)	Poglino	T25°C	V _I = 10.5V to 25V	-	5.0	160	mV
Line Regulation (Note1)	Regline	TJ =+25°C	V _I = 11.5V to 17V	-	2.0	80	IIIV
Load Regulation (Note1)	Pagland	TJ =+25°C	I _O = 5.0mA to 1.5A	-	10	160	mV
Load Regulation (Note1)	Regload		IO= 250mA to 750mA	-	5.0	80	IIIV
Quiescent Current	IQ	TJ =+25°C		-	5.0	8.0	mA
Quiagant Current Change	41-	IO = 5mA to 1.0	A	-	0.05	0.5	mA
Quiescent Current Change	ΔlQ	V _I = 10.5A to 25	V	-	0.5	1.0	IIIA
Output Voltage Drift (Note2)	ΔV0/ΔΤ	IO = 5mA		-	-0.8	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kH	Iz, T _A = +25°C	-	52	-	μV/Vo
Ripple Rejection (Note2)	RR	f = 120Hz, V _I = 1	11.5V to 21.5V	56	73	-	dB
Dropout Voltage	V _{Drop}	I _O = 1A, T _J = +25°C		-	2	-	V
Output Resistance (Note2)	ro	f = 1kHz		-	17	-	mΩ
Short Circuit Current	Isc	VI = 35V, TA = +	-25°C	-	230	-	mA
Peak Current (Note2)	IPK	TJ =+25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

^{2.} These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (MC7809E) (Continued)

(Refer to test circuit $,0^{\circ}C < T_{J} < 125^{\circ}C, I_{O} = 500 \text{mA}, V_{I} = 15 \text{V}, C_{I} = 0.33 \mu\text{F}, C_{O} = 0.1 \mu\text{F}, unless otherwise specified})$

Boromotor	Cymbol	C	anditions	M	C7809	E	Unit
Parameter	Symbol		onditions	Min.	Тур.	Max.	Unit
		T _J = +25°C		8.65	9	9.35	
Output Voltage	Vo		$5.0 \text{mA} \le I_{\text{O}} \le 1.0 \text{A}, P_{\text{O}} \le 15 \text{W}$ VI = 11.5V to 24V		9	9.4	V
Line Population (Note1)	Poglino	T _J = +25°C	V _I = 11.5V to 25V	-	6	180	mV
Line Regulation (Note1)	Regline	1J = +25 C	V _I = 12V to 17V	-	2	90	IIIV
Load Population (Note1)	Regload	T _J = +25°C	I _O = 5mA to 1.5A	-	12	180	mV
Load Regulation (Note1)	Regioau		IO = 250mA to 750mA	-	4	90	IIIV
Quiescent Current	lQ	T _J = +25°C		-	5.0	8.0	mA
Ouissant Current Change	Alo	IO = 5mA to 1.0A	4	-	-	0.5	m 1
Quiescent Current Change	ΔlQ	V _I = 11.5V to 26	V	-	-	1.3	mA
Output Voltage Drift (Note2)	ΔV0/ΔΤ	IO = 5mA		-	-1	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kH	lz, T _A = +25°C	-	58	-	μV/Vo
Ripple Rejection (Note2)	RR	f = 120Hz V _I = 13V to 23V		56	71	-	dB
Dropout Voltage	VDrop	IO = 1A, TJ = +25°C		-	2	-	V
Output Resistance (Note2)	ro	f = 1kHz		-	17	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A = +25°C		-	250	-	mA
Peak Current (Note2)	IPK	T _J = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

^{2.} These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (MC7812E) (Continued)

(Refer to test circuit ,0°C < TJ < 125°C, IO = 500mA, VI =19V, CI= $0.33\mu F$, CO= $0.1\mu F$, unless otherwise specified)

Parameter	Symbol	C	onditions	M	C7812	E	Unit
Parameter	Symbol		onations	Min.	Тур.	Max.	Unit
		T _J = +25°C		11.5	12	12.5	
Output Voltage	Vo	5.0mA ≤ I _O ≤ 1.0 V _I = 14.5V to 27\		11.4	12	12.6	V
Line Regulation (Note1)	Regline	T _J = +25°C	V _I = 14.5V to 30V	-	10	240	mV
Line Regulation (Note I)	Regime	1J = +25 C	VI = 16V to 22V	-	3.0	120	IIIV
Load Regulation (Note1)	Regload	T _J = +25°C	I _O = 5mA to 1.5A	-	11	240	mV
Load Regulation (Note1)	Regioau	1) = +25 0	IO = 250mA to 750mA	-	5.0	120	IIIV
Quiescent Current	lQ	T _J = +25°C	T _J = +25°C		5.1	8.0	mA
Quiagant Current Change	Ma	IO = 5mA to 1.0A	1	-	0.1	0.5	mA
Quiescent Current Change	ΔlQ	V _I = 14.5V to 30\	I	-	0.5	1.0	MA
Output Voltage Drift (Note2)	ΔV0/ΔΤ	IO = 5mA		-	-1	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kHz	z, T _A = +25°C	-	76	-	μV/Vo
Ripple Rejection (Note2)	RR	f = 120Hz VI = 15V to 25V		55	71	-	dB
Dropout Voltage	VDrop	IO = 1A, TJ = +25°C		-	2	-	V
Output Resistance (Note2)	ro	f = 1kHz		-	18	-	mΩ
Short Circuit Current	Isc	VI = 35V, T _A = +2	25°C	-	230	-	mA
Peak Current (Note2)	IPK	T _J = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

^{2.} These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (MC7815E) (Continued)

(Refer to test circuit ,0°C < TJ < 125°C, IO = 500mA, VI =23V, CI= 0.33 μ F, CO=0.1 μ F, unless otherwise specified)

Parameter	Cumbal	6.	onditions	N	IC7815I	Ē	I I m i 4
Parameter	Symbol		onaitions	Min.	Тур.	Max.	Unit
		TJ =+25°C		14.4	15	15.6	
Output Voltage	Vo	$5.0 \text{mA} \le I_0 \le 7$ V _I = 17.5V to 3	1.0A, P _O ≤ 15W 30V	14.25	15	15.75	V
Line Regulation (Note1)	Poglino	T _J = +25°C	V _I = 17.5V to 30V	-	11	300	mV
Line Regulation (Note I)	Regline	1J = +25 C	VI = 20V to 26V	-	3	150	IIIV
			I _O = 5mA to 1.5A	-	12	300	
Load Regulation (Note1)	Regload		IO = 250mA to 750mA	-	4	150	mV
Quiescent Current	IQ	TJ =+25°C	TJ =+25°C		5.2	8.0	mA
Quiescent Current Change	Alo.	$I_O = 5mA \text{ to } 1$.0A	-	-	0.5	mA
Quiescent Current Change	ΔlQ	VI = 17.5V to 3	30V	-	-	1.0	IIIA
Output Voltage Drift (Note2)	ΔV0/ΔΤ	I _O = 5mA		-	-1	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100	kHz, TA = +25°C	-	90	-	μV/Vo
Ripple Rejection (Note2)	RR	f = 120Hz V _I = 18.5V to 2	f = 120Hz V _I = 18.5V to 28.5V		70	-	dB
Dropout Voltage	V _{Drop}	I _O = 1A, T _J =+25°C		-	2	-	V
Output Resistance (Note2)	rO	f = 1kHz		-	19	-	mΩ
Short Circuit Current	Isc	VI = 35V, TA = +25°C		-	250	-	mA
Peak Current (Note2)	IPK	TJ =+25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

^{2.} These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (MC7818E) (Continued)

(Refer to test circuit ,0°C < TJ < 125°C, IO = 500mA, VI = 27V, CI = 0.33 μ F, CO= 0.1 μ F, unless otherwise specified)

Parameter	Cymbal	C	anditions	M	C7818	E	l lni4
Parameter	Symbol		onditions	Min.	Тур.	Max.	Unit
		T _J =+25°C		17.3	18	18.7	
Output Voltage	Vo	5.0mA ≤ I _O ≤1.0A VI = 21V to 33V	A, P _O ≤15W	17.1	18	18.9	V
Line Regulation (Note1)	Regline	T _J =+25°C	V _I = 21V to 33V	-	15	360	mV
Line Regulation (Note I)	regime	1J = 1 23 C	VI = 24V to 30V	-	5	180	IIIV
Load Population (Note1)	Regload	T _J =+25°C	I _O = 5mA to 1.5A	-	15	360	mV
Load Regulation (Note1)	Regioau	1J =+25 C	IO = 250mA to 750mA	-	5.0	180	IIIV
Quiescent Current	IQ	T _J = +25°C		-	5.2	8.0	mA
Quioscont Current Change	Alo.	IO = 5mA to 1.0A		-	-	0.5	mA
Quiescent Current Change	ΔlQ	V _I = 21V to 33V		-	-	1	IIIA
Output Voltage Drift (Note2)	ΔVο/ΔΤ	IO = 5mA		-	-1	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kH	z, T _A = +25°C	-	110	-	μV/Vo
Ripple Rejection (Note2)	RR	f = 120Hz VI = 22V to 32V		53	69	-	dB
Dropout Voltage	VDrop	IO = 1A, TJ = +25°C		-	2	-	V
Output Resistance (Note2)	ro	f = 1kHz		-	22	-	mΩ
Short Circuit Current	Isc	VI = 35V, TA = +2	25°C	-	250	-	mA
Peak Current (Note2)	lpk	T _J = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

^{2.} These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (MC7824E) (Continued)

(Refer to test circuit ,0°C < TJ < 125°C, IO = 500mA, VI =33V, CI= 0.33 μ F, CO=0.1 μ F, unless otherwise specified)

Donomotor	Cumbal	C	onditions	М	C7824	ΙE	Unit
Parameter	Symbol		onaitions	Min.	Тур.	Max.	Unit
		T _J = +25°C		23	24	25	
Output Voltage	Vo	5.0mA ≤ I _O ≤ 1.0 V _I = 27V to 38V	A, P _O ≤ 15W	22.8	24	25.25	V
Line Regulation (Note1)	Regline	T,j = +25°C	V _I = 27V to 38V	-	17	480	mV
Line Regulation (Note I)	Regilile	1J = +25 C	VI = 30V to 36V	-	6	240	IIIV
Load Population (Note1)	Regload	TJ = +25°C	I _O = 5mA to 1.5A	-	15	480	mV
Load Regulation (Note1)	Regioad	1J = 72J C	IO = 250mA to 750mA	-	5.0	240	IIIV
Quiescent Current	IQ	T _J = +25°C		-	5.2	8.0	mA
Outageant Current Change	41-	IO = 5mA to 1.0A	1	-	0.1	0.5	A
Quiescent Current Change	ΔlQ	V _I = 27V to 38V		-	0.5	1	mA
Output Voltage Drift (Note2)	ΔV0/ΔΤ	IO = 5mA		-	-1.5	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kH	z, T _A = +25°C	-	60	-	μV/Vo
Ripple Rejection (Note2)	RR	f = 120Hz VI = 28V to 38V		50	67	-	dB
Dropout Voltage	VDrop	IO = 1A, TJ= +25°C		-	2	-	V
Output Resistance (Note2)	rO	f = 1kHz		-	28	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A = +25°C		-	230	-	mA
Peak Current (Note2)	IPK	T _J = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Changes in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

^{2.} These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (MC7805AE) (Continued)

(Refer to the test circuits. 0° C < T_J < 125° C, I_0 =1A, V I = 10V, C I=0.33 μ F, C O=0.1 μ F, unless otherwise specified)

Parameter	Symbol	Co	onditions	Min.	Тур.	Max.	Unit
		T _J = +25°C		4.9	5	5.1	
Output Voltage	Vo	I _O = 5mA to 1. V _I = 7.5V to 2		4.8	5	5.2	V
		$V_I = 7.5V \text{ to } 25$	5V, IO = 500mA	-	5	50	
Line Regulation (Note1)	Regline	V _I = 8V to 12V	/	-	3	50	mV
	ixegiirie	T,j = +25°C	V _I = 7.3V to 20V	-	5	50	IIIV
		TJ = +25°C	V _I = 8V to 12V	-	1.5	25	
1 15 16 (11)		TJ = +25°C, I() = 5mA to 1.5A	-	9	100	
Load Regulation (Note1)	Regload	I _O = 5mA to 1	I _O = 5mA to 1A		9	100	mV
		IO = 250mA to 750mA		-	4	50	
Quiescent Current	IQ	T _J = +25°C		-	5.0	6	mA
		IO = 5mA to 1	A	-	-	0.5	
Quiescent Current Change	Δ lQ	V _I = 8 V to 25V, I _O = 500mA		-	-	0.8	mA
		V _I = 7.5V to 20V, T _J = +25°C		-	-	0.8	
Output Voltage Drift (Note2)	ΔV/ΔΤ	lo = 5mA		-	-0.8	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 10 TA =+25°C	0kHz	-	10	-	μV/Vο
Ripple Rejection (Note2)	RR	, -	f = 120Hz, I _O = 500mA V _I = 8V to 18V		68	-	dB
Dropout Voltage	VDrop	IO = 1A, TJ =+25°C		-	2	-	V
Output Resistance (Note2)	ro	f = 1kHz		-	17	-	mΩ
Short Circuit Current	Isc	VI = 35V, TA =	=+25°C	-	250	-	mA
Peak Current (Note2)	IPK	TJ = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

^{2.} These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (MC7806AE) (Continued)

(Refer to the test circuits. 0° C < T_J < 125° C, I_0 =1A, V I =11V, C I=0.33 μ F, C O=0.1 μ F, unless otherwise specified)

Parameter	Symbol	Co	onditions	Min.	Тур.	Max.	Unit
		T _J =+25°C		5.58	6	6.12	
Output Voltage	Vo	I _O = 5mA to 1 V _I = 8.6V to 2		5.76	6	6.24	V
		$V_{I} = 8.6V \text{ to } 2$	5V, IO = 500mA	-	5	60	
Line Regulation (Note1)	Dogling	V _I = 9V to 13\	/	-	3	60	mV
	Regline	T05°C	V _I = 8.3V to 21V	-	5	60	IIIV
		TJ =+25°C	V _I = 9V to 13V	-	1.5	30	
1 15 14 (1)		TJ =+25°C, IC) = 5mA to 1.5A	-	9	100	
Load Regulation (Note1)	Regload	I _O = 5mA to 1	A	-	4	100	mV
		IO = 250mA to 750mA		-	5.0	50	
Quiescent Current	IQ	TJ =+25°C		-	4.3	6	mA
	ΔlQ	IO = 5mA to 1	A	-	-	0.5	
Quiescent Current Change		V _I = 9V to 25V, I _O = 500mA		-	-	8.0	mA
		V _I = 8.5V to 21V, T _J = +25°C		-	-	0.8	
Output Voltage Drift (Note2)	ΔV/ΔΤ	I _O = 5mA		-	-0.8	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 10 TA = +25°C	00kHz	-	10	-	μV/Vο
Ripple Rejection (Note2)	RR	f = 120Hz, I _O = 500mA V _I = 9V to 19V		-	65	-	dB
Dropout Voltage	VDrop	IO = 1A, TJ = +25°C		-	2	-	V
Output Resistance (Note2)	rO	f = 1kHz		-	17	-	mΩ
Short Circuit Current	Isc	VI = 35V, TA =	=+25°C	-	250	•	mA
Peak Current (Note2)	lpk	TJ = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

^{2.} These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (MC7808AE) (Continued)

(Refer to the test circuits. 0° C < T_J < 125° C, I_0 =1A, V I = 14V, C I=0.33 μ F, C I=0.1 μ F, unless otherwise specified)

Parameter	Symbol	Co	onditions	Min.	Тур.	Max.	Unit
		TJ =+25°C		7.84	8	8.16	
Output Voltage	Vo	IO = 5mA to 1 V _I = 10.6V to	, -	7.7	8	8.3	V
		V _I = 10.6V to 2	25V, IO = 500mA	-	6	80	
Line Regulation (Note1)	Dogling	V _I = 11V to 17	·V	-	3	80	\/
	Regline	T 25°C	V _I = 10.4V to 23V	-	6	80	mV
		TJ =+25°C	V _I = 11V to 17V	-	2	40	
1 15 13 01 0		TJ =+25°C, IC) = 5mA to 1.5A	-	12	100	
Load Regulation (Note1)	Regload	I _O = 5mA to 1	A	-	12	100	mV
		I _O = 250mA to	I _O = 250mA to 750mA		5	50	
Quiescent Current	IQ	TJ =+25°C		-	5.0	6	mA
		I _O = 5mA to 1	A	-	-	0.5	
Quiescent Current Change	ΔlQ	V _I = 11V to 25V, I _O = 500mA		-	-	0.8	mA
		V _I = 10.6V to 23V, T _J =+25°C		-	-	0.8	1
Output Voltage Drift (Note2)	ΔV/ΔΤ	IO = 5mA		-	-0.8	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 10 TA =+25°C	00kHz	-	10	-	μV/Vo
Ripple Rejection (Note2)	RR	f = 120Hz, I _O = 500mA V _I = 11.5V to 21.5V		-	62	-	dB
Dropout Voltage	V _{Drop}	I _O = 1A, T _J =+25°C		-	2	-	V
Output Resistance (Note2)	ro	f = 1kHz		-	18	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A :	=+25°C	-	250	-	mA
Peak Current (Note2)	IPK	TJ = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Change in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

^{2.} These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (MC7809AE) (Continued)

(Refer to the test circuits. 0° C < T_J < 125° C, I_0 =1A, V I = 15V, C I=0.33 μ F, C I=0.1 μ F, unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
		T _J = +25°C		8.82	9.0	9.18	V
Output Voltage	Vo	I _O = 5mA to 1A, P _O ≤ 15W V _I = 11.2V to 24V		8.65	9.0	9.35	
		VI = 11.7V to	V _I = 11.7V to 25V, I _O = 500mA		6	90	
Line Regulation (Note1)	Regline	V _I = 12.5V to 1	19V	-	4	45	- mV
	Regilile	T. 125°C	V _I = 11.5V to 24V	-	6	90	
		TJ =+25°C -	V _I = 12.5V to 19V	-	2	45	
		TJ =+25°C, IC) = 5mA to 1.0A	-	12	100	
Load Regulation (Note1)	Regload	I _O = 5mA to 1.0A		-	12	100	mV
		IO = 250mA to	IO = 250mA to 750mA		5	50	1
Quiescent Current	IQ	T _J = +25°C		-	5.0	6.0	mA
	ΔlQ	V _I = 11.7V to 25V, T _J = +25°C		-	-	8.0	
Quiescent Current Change		V _I = 12V to 25V, I _O = 500mA		-	-	8.0	mA
		IO = 5mA to 1.0A		-	-	0.5	
Output Voltage Drift (Note2)	ΔV/ΔΤ	I _O = 5mA		-	-1.0	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kHz TA = +25°C		-	10	-	μV/Vo
Ripple Rejection (Note2)	RR	f = 120Hz, I _O = 500mA V _I = 12V to 22V		-	62	-	dB
Dropout Voltage	VDrop	IO = 1A, TJ =+25°C		-	2.0	-	V
Output Resistance (Note2)	rO	f = 1kHz		-	17	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A = +25°C		-	250	-	mA
Peak Current (Note2)	IPK	T _J = +25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant, junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

^{2.} These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (MC7812AE) (Continued)

(Refer to the test circuits. 0° C < T_J < 125° C, I_0 =1A, V I = 19V, C I=0.33 μ F, CO=0.1 μ F, unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
	T _J =+25°C		11.75	12	12.25		
Output Voltage	Vo		I _O = 5mA to 1A, P _O ≤15W V _I = 14.8V to 27V		12	12.5	V
		V _I = 14.8V to 3	V _I = 14.8V to 30V, I _O = 500mA		10	120	
Line Regulation (Note1)	Doglino	V _I = 16V to 22	V	-	4	120	>/
	Regline	T 25°C	V _I = 14.5V to 27V	-	10	120	mV
		TJ =+25°C	V _I = 16V to 22V	-	3	60	1
		TJ =+25°C, IC	= 5mA to 1.5A	-	12	100	
Load Regulation (Note1)	Regload	I _O = 5mA to 1.0A		-	12	100	mV
		IO = 250mA to 750mA		-	5	50	
Quiescent Current	IQ	T _J =+25°C		-	5.1	6.0	mA
	ΔlQ	V _I = 15V to 30V, T _J =+25°C		-		0.8	
Quiescent Current Change		V _I = 14V to 27V, I _O = 500mA		-		8.0	mA
		IO = 5mA to 1.0A		-		0.5	
Output Voltage Drift (Note2)	ΔV/ΔΤ	I _O = 5mA		-	-1.0	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kHz TA =+25°C		-	10	-	μV/Vo
Ripple Rejection (Note2)	RR	f = 120Hz, I _O = 500mA V _I = 14V to 24V		-	60	-	dB
Dropout Voltage	VDrop	IO = 1A, TJ =+25°C		-	2.0	-	V
Output Resistance (Note2)	rO	f = 1kHz		-	18	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A =+25°C		-	250	-	mA
Peak Current (Note2)	IPK	TJ=+25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Change in Vo due to heating effects must be taken into account separately. Pulse testing with low duty is used.

^{2.} These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (MC7815AE) (Continued)

(Refer to the test circuits. 0° C < T_J < 125° C, I_0 =1A, V I =23V, C I=0.33 μ F, CO=0.1 μ F, unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
		T _J =+25°C		14.7	15	15.3	
Output Voltage	Vo		I _O = 5mA to 1A, P _O ≤15W V _I = 17.7V to 30V		15	15.6	V
		V _I = 17.9V to	V _I = 17.9V to 30V, I _O = 500mA		10	150	
Line Regulation (Note1)	Regline	V _I = 20V to 26	V	-	5	150	mV
	Regilile	TJ =+25°C	V _I = 17.5V to 30V	-	11	150	
		1J =+25 C	V _I = 20V to 26V	-	3	75	
1 15 13 (1)		TJ =+25°C, IC	= 5mA to 1.5A	-	12	100	
Load Regulation (Note1)	Regload	IO = 5mA to 1.0A		-	12	100	mV
		IO = 250mA to 750mA		-	5	50	
Quiescent Current	IQ	T _J =+25°C		-	5.2	6.0	mA
		V _I = 17.5V to 30V, T _J =+25°C		-	-	0.8	
Quiescent Current Change	ΔlQ	V _I = 17.5V to 30V, I _O = 500mA		-	-	0.8	mA
		I _O = 5mA to 1.0A		-	-	0.5	
Output Voltage Drift (Note2)	ΔV/ΔΤ	IO = 5mA		-	-1.0	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kHz TA =+25°C		-	10	-	μV/Vo
Ripple Rejection (Note2)	RR	f = 120Hz, I _O = 500mA V _I = 18.5V to 28.5V		-	58	-	dB
Dropout Voltage	VDrop	Io = 1A, T _J =+25°C		-	2.0	-	V
Output Resistance (Note2)	ro	f = 1kHz		-	19	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A =+25°C		-	250	-	mA
Peak Current (Note2)	IPK	T _J =+25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

^{2.} These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (MC7818AE) (Continued)

(Refer to the test circuits. 0° C < T_J < 125° C, I_0 =1A, V I = 27V, C I=0.33 μ F, C I=0.1 μ F, unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
		T _J =+25°C		17.64	18	18.36	٧
Output Voltage	Vo		$I_O = 5mA \text{ to } 1A, P_O \le 15W$ $V_I = 21V \text{ to } 33V$		18	18.7	
		V _I = 21V to 33	V _I = 21V to 33V, I _O = 500mA		15	180	
Line Regulation (Note1)	Regline	V _I = 21V to 33	V	-	5	180	mV
	Regime	TJ =+25°C	V _I = 20.6V to 33V	-	15	180	
		1J =+25°C	V _I = 24V to 30V	-	5	90	
1 15 14 (11 (1)		TJ =+25°C, IC) = 5mA to 1.5A	-	15	100	
Load Regulation (Note1)	Regload	I _O = 5mA to 1.0A		-	15	100	mV
		IO = 250mA to 750mA		-	7	50	
Quiescent Current	IQ	T _J =+25°C		-	5.2	6.0	mA
	V _I = 21V to 33V, T _J		3V, TJ=+25°C	-	-	0.8	
Quiescent Current Change	ΔlQ	V _I = 21V to 33V, I _O = 500mA		-	-	0.8	mA
		IO = 5mA to 1.0A		-	-	0.5]
Output Voltage Drift (Note2)	ΔV/ΔΤ	IO = 5mA		-	-1.0	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kHz TA =+25°C		-	10	-	μV/Vo
Ripple Rejection (Note2)	RR	f = 120Hz, I _O = 500mA V _I = 22V to 32V		-	57	-	dB
Dropout Voltage	VDrop	IO = 1A, TJ =+25°C		-	2.0	-	V
Output Resistance (Note2)	rO	f = 1kHz		-	19	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A =+25°C		-	250	-	mA
Peak Current (Note2)	IPK	TJ=+25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

^{2.} These parameters, although guaranteed, are not 100% tested in production.

Electrical Characteristics (MC7824AE) (Continued)

(Refer to the test circuits. 0° C < T_J < 125° C, I_0 =1A, V I = 33V, C I=0.33 μ F, CO=0.1 μ F, unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
	T _J =+25°C			23.5	24	24.5	
Output Voltage	Vo		I _O = 5mA to 1A, P _O ≤15W V _I = 27.3V to 38V		24	25	V
		V _I = 27V to 38	V _I = 27V to 38V, I _O = 500mA		18	240	
Line Regulation (Note1)	Regline	V _I = 21V to 33	V	-	6	240	- mV
	Regilile	T. 125°C	V _I = 26.7V to 38V	-	18	240	
		TJ =+25°C	V _I = 30V to 36V	-	6	120	
1 15 14 (11 (1)		TJ =+25°C, IC) = 5mA to 1.5A	-	15	100	
Load Regulation (Note1)	Regload	I _O = 5mA to 1.0A		-	15	100	mV
		IO = 250mA to 750mA		-	7	50	
Quiescent Current	IQ	T _J =+25°C		-	5.2	6.0	mA
		VI = 27.3V to	38V, TJ =+25°C	-	-	0.8	
Quiescent Current Change	ΔlQ	V _I = 27.3V to 38V, I _O = 500mA		-	-	0.8	mA
		IO = 5mA to 1.0A		-	-	0.5	
Output Voltage Drift (Note2)	ΔV/ΔΤ	I _O = 5mA		-	-1.5	-	mV/°C
Output Noise Voltage	VN	f = 10Hz to 100kHz TA = 25°C		-	10	-	μV/Vo
Ripple Rejection (Note2)	RR	f = 120Hz, I _O = 500mA V _I = 28V to 38V		-	54	-	dB
Dropout Voltage	VDrop	IO = 1A, TJ =+25°C		-	2.0	-	V
Output Resistance (Note2)	rO	f = 1kHz		-	20	-	mΩ
Short Circuit Current	Isc	V _I = 35V, T _A =+25°C		-	250	-	mA
Peak Current (Note2)	IPK	T _J =+25°C		-	2.2	-	Α

^{1.} Load and line regulation are specified at constant junction temperature. Change in VO due to heating effects must be taken into account separately. Pulse testing with low duty is used.

^{2.} These parameters, although guaranteed, are not 100% tested in production.

Typical Perfomance Characteristics

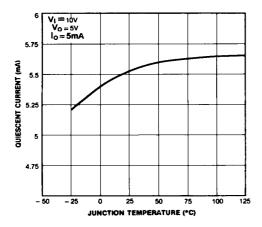


Figure 1. Quiescent Current

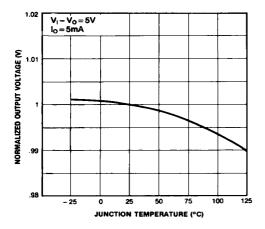


Figure 3. Output Voltage

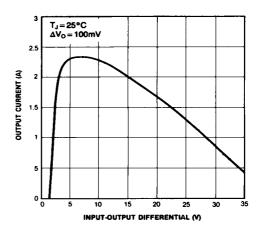


Figure 2. Peak Output Current

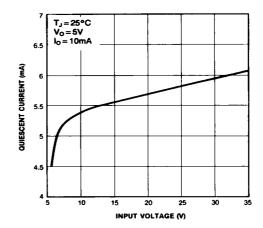


Figure 4. Quiescent Current

Typical Applications

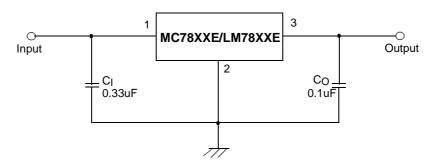


Figure 5. DC Parameters

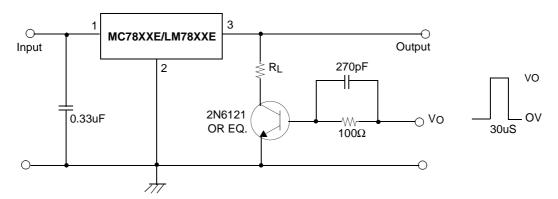


Figure 6. Load Regulation

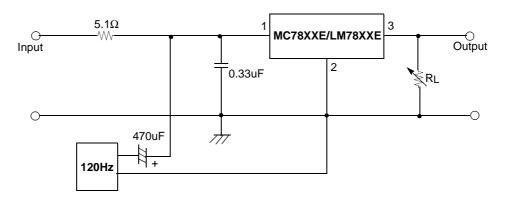


Figure 7. Ripple Rejection

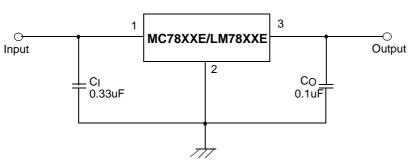


Figure 8. Fixed Output Regulator

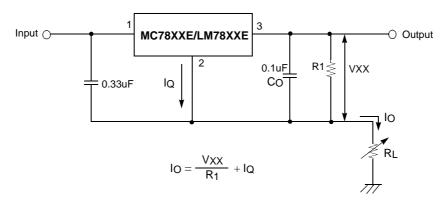


Figure 9. Constant Current Regulator

- (1) To specify an output voltage. substitute voltage value for "XX." A common ground is required between the input and the Output voltage. The input voltage must remain typically 2.0V above the output voltage even during the low point on the input ripple voltage.
- (2) C_I is required if regulator is located an appreciable distance from power Supply filter.
- (3) Co improves stability and transient response.

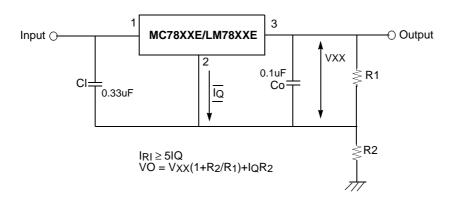


Figure 10. Circuit for Increasing Output Voltage

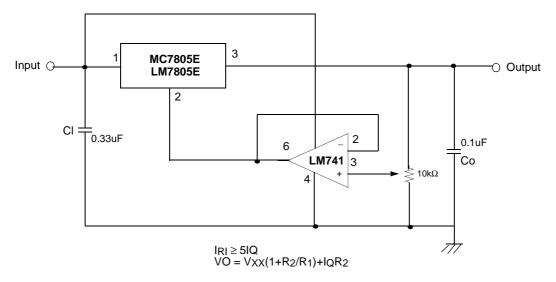


Figure 11. Adjustable Output Regulator (7 to 30V)

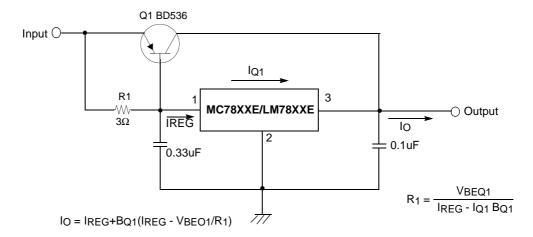


Figure 12. High Current Voltage Regulator

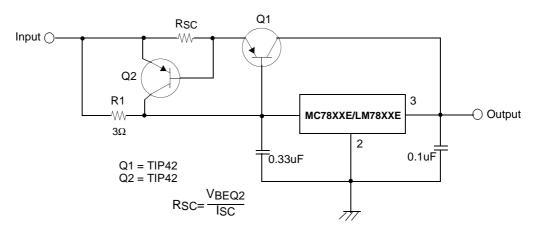


Figure 13. High Output Current with Short Circuit Protection

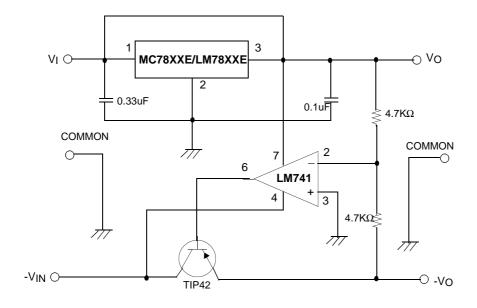


Figure 14. Tracking Voltage Regulator

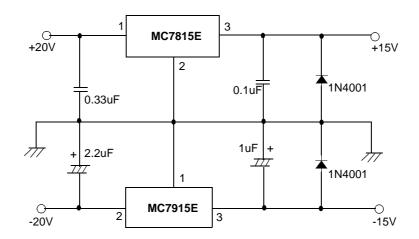


Figure 15. Split Power Supply (±15V-1A)

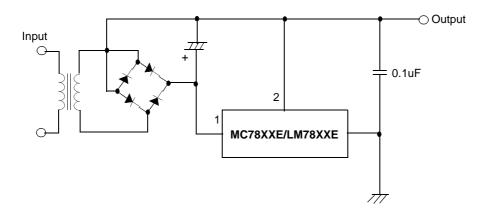


Figure 16. Negative Output Voltage Circuit

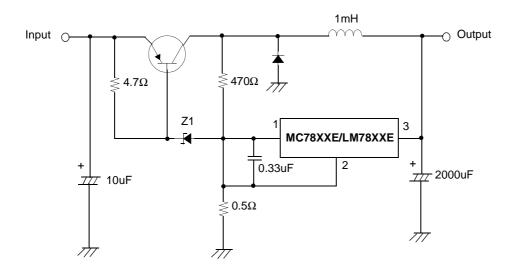


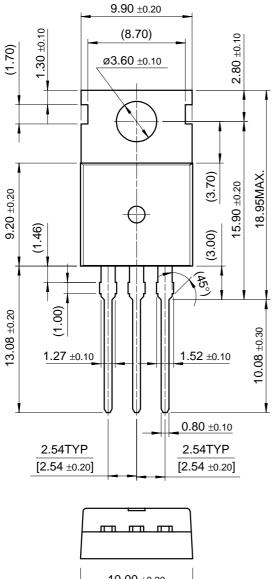
Figure 17. Switching Regulator

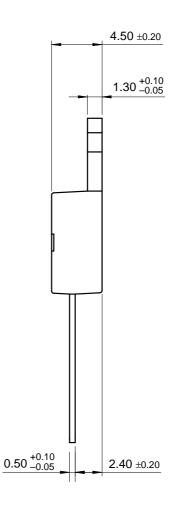
Mechanical Dimensions

Package

Dimensions in millimeters

TO-220

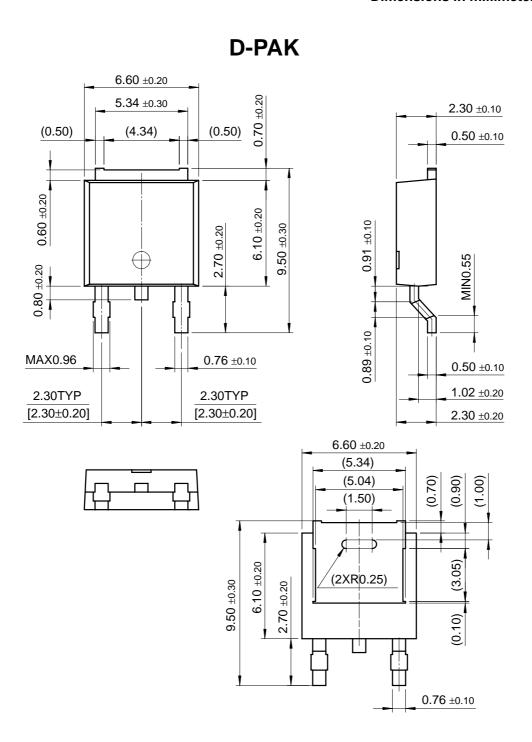




Mechancal Dimensions (Continued)

Package

Dimensions in millimeters



Ordering Information

Product Number	Output Voltage Tolerance	Package	Operating Temperature
LM7805ECT	±4%	TO-220	0 ~ +125°C
Product Number	Output Voltage Tolerance	Package	Operating Temperature
MC7805ECT			
MC7806ECT			
MC7808ECT			
MC7809ECT		TO-220	
MC7812ECT		10-220	
MC7815ECT			
MC7818ECT	±4%		
MC7824ECT			
MC7805ECDT			
MC7806ECDT			
MC7808ECDT		D-PAK	0 ~ +125°C
MC7809ECDT			
MC7812ECDT			
MC7805AECT			
MC7806AECT			
MC7808AECT			
MC7809AECT	+2%	TO-220	
MC7812AECT	± ∠ 70	10-220	
MC7815AECT			
MC7818AECT			
MC7824AECT			

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